TOSHIBA Diode Silicon Epitaxial Schottky Barrier Type

# **HN2S01F**

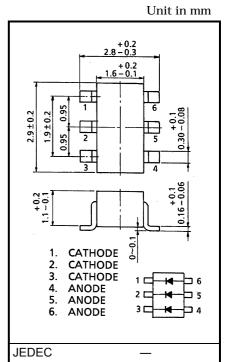
Low Voltage High Speed Switching Application

- HN2S01F is composed of 3 independent diodes.
- Low reverse current: V<sub>F</sub> = 0.23V (typ.) @I<sub>F</sub> = 5mA

### **Maximum Ratings (Ta = 25°C)**

Characteristic	Symbol	Rating	Unit
Maximum (peak) reverse Voltage	$V_{RM}$	15	V
Reverse voltage	V <sub>R</sub>	10	٧
Maximum (peak) forward current	I <sub>FM</sub>	200 *	mA
Average forward current	Io	100 *	mA
Surge current (10ms)	I <sub>FSM</sub>	1 *	Α
Power dissipation	Р	300	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	−55~125	°C
Operating temperature range	T <sub>opr</sub>	<del>-</del> 40~100	°C

 $<sup>^*</sup>$ : This is maximum rating of single diode (Q1 or Q2 or Q3). In the case of using 2 ro 3 diodes, the maximum ratings per diodes is 75 % of the single diode one.



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1-3K1C

Weight: 0.015g

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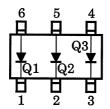
#### Electrical Characteristics (Q1, Q2, Q3 Common, Ta = 25°C)

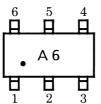
Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit	
Forward voltage	V <sub>F (1)</sub>	_	I <sub>F</sub> = 1mA	_	0.18	_		
	V <sub>F (2)</sub>	_	I <sub>F</sub> = 5mA	_	0.23	0.30	٧	
	V <sub>F (3)</sub>	_	I <sub>F</sub> = 100mA	_	0.35	0.50		
Reverse current	I <sub>R</sub>	_	V <sub>R</sub> = 10V	_	_	20	μA	
Total capacitance	Ст	_	V <sub>R</sub> = 0, f = 1MH <sub>z</sub>	ı	20	40	pF	

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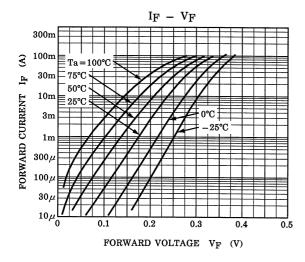
## **Pin Assignment (Top View)**

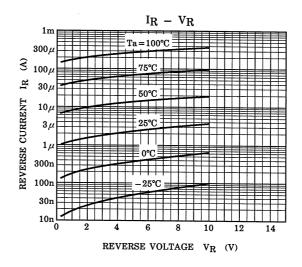
## Marking

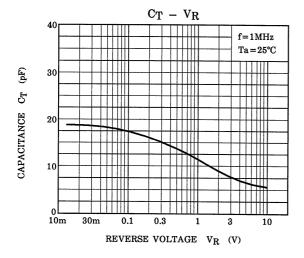


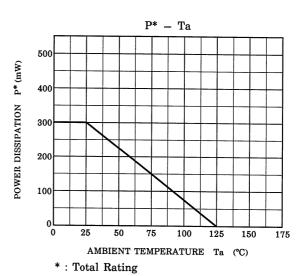


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